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# Update: Stability of APAM Doping in Si

## November, 14<sup>th</sup>, 2022

*PRESENTED BY*

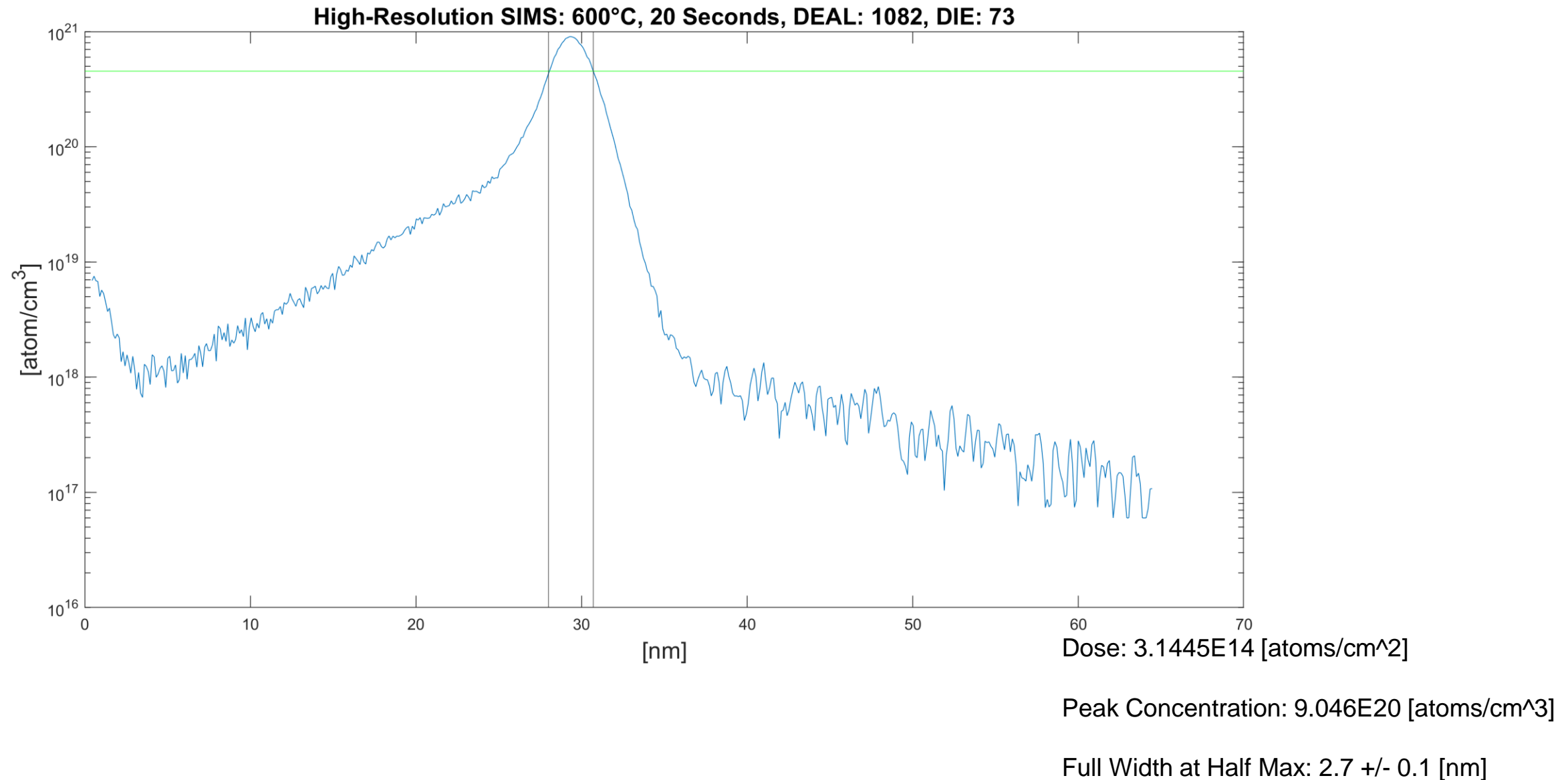
Panagiotis Panoutsopoulos, & Dr. Kevin Jones



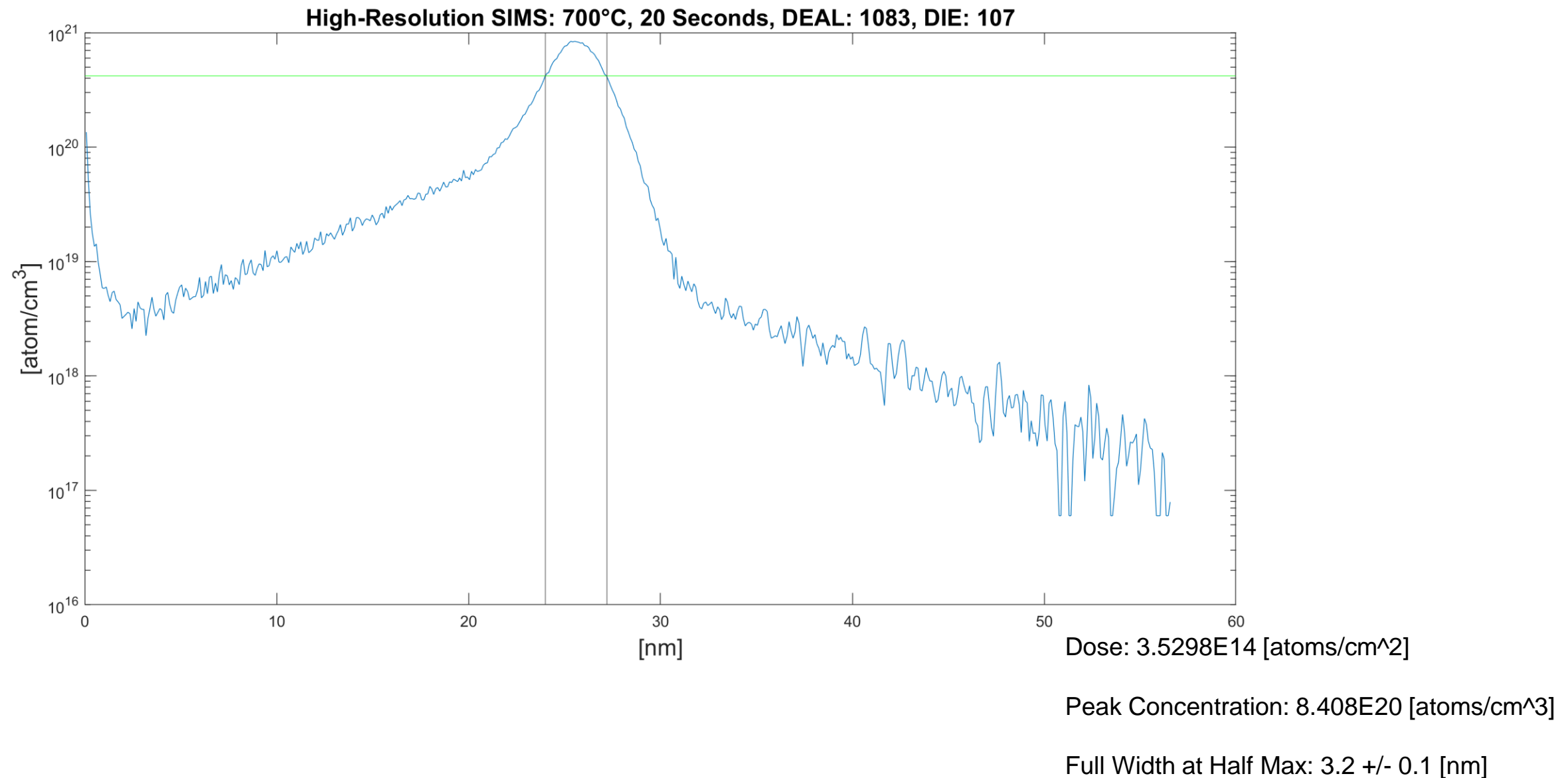
**Sandia  
National  
Laboratories**



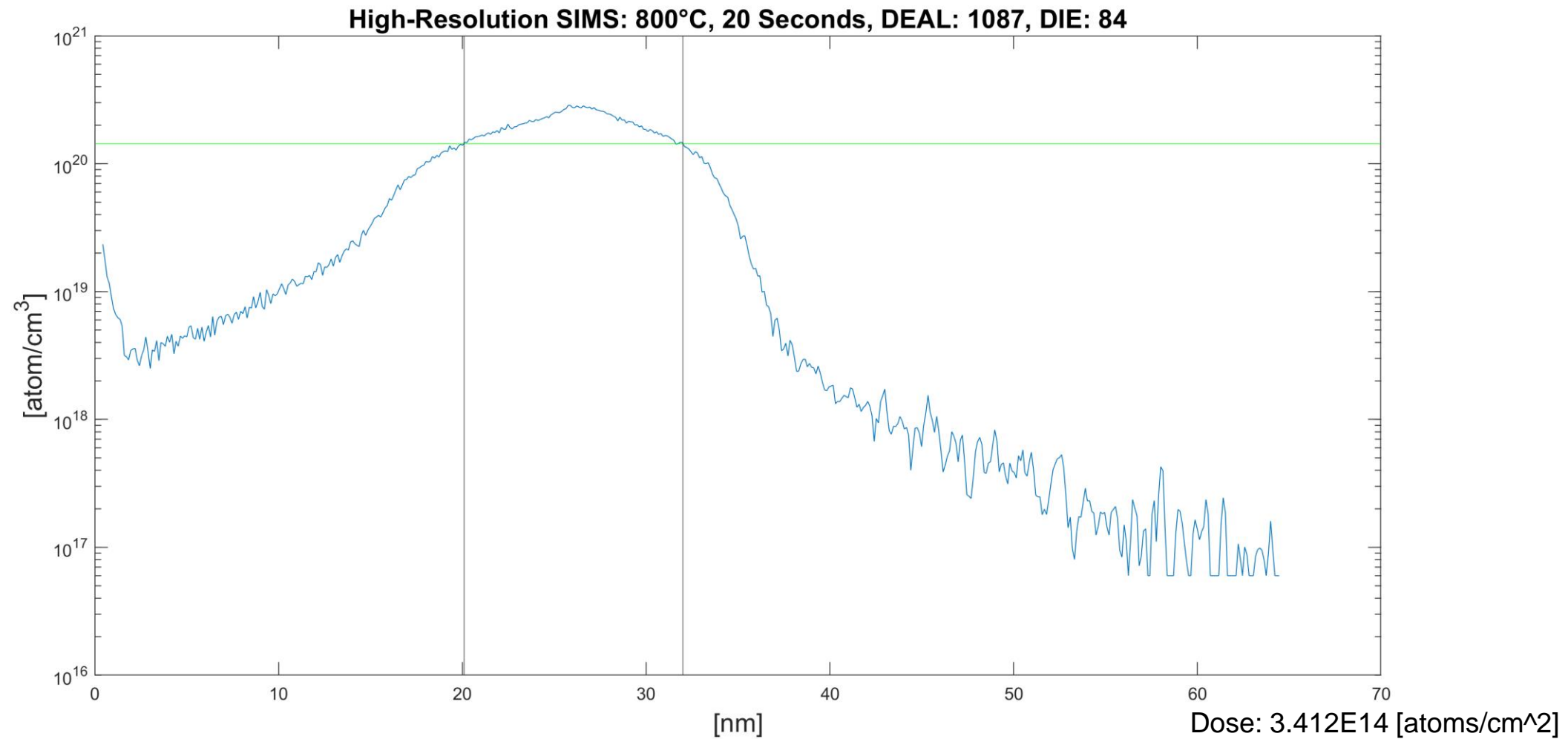
# High-Resolution SIMS: Double Dose, 600C, 20s



# High-Resolution SIMS: Double Dose, 700C, 20s



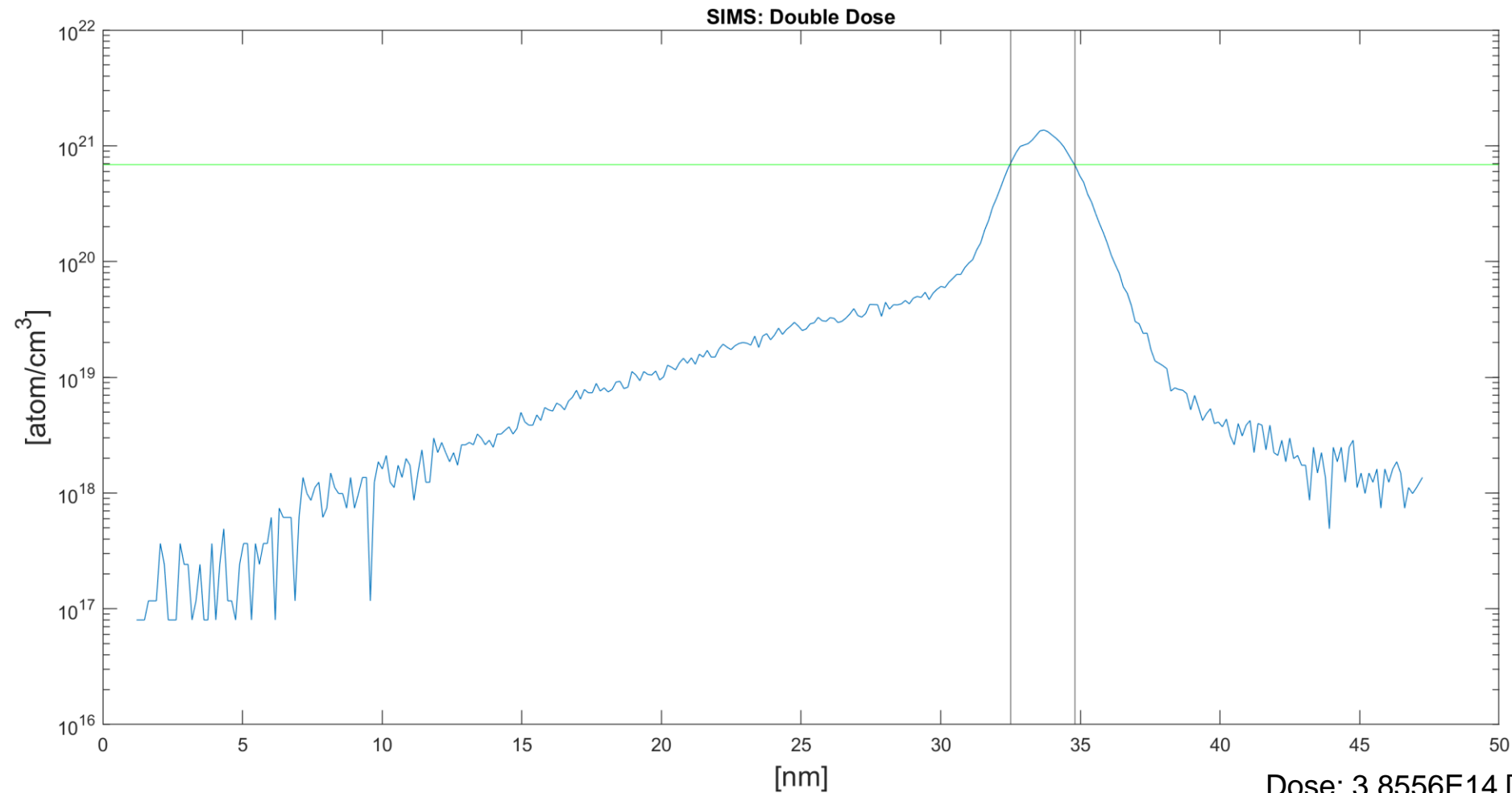
# High-Resolution SIMS: Double Dose, 800C, 20s



Peak Concentration: 2.858E20 [atoms/cm<sup>3</sup>]

Full Width at Half Max: 11.9 +/- 0.1 [nm]

# High-Resolution SIMS: Double Dose As Grown

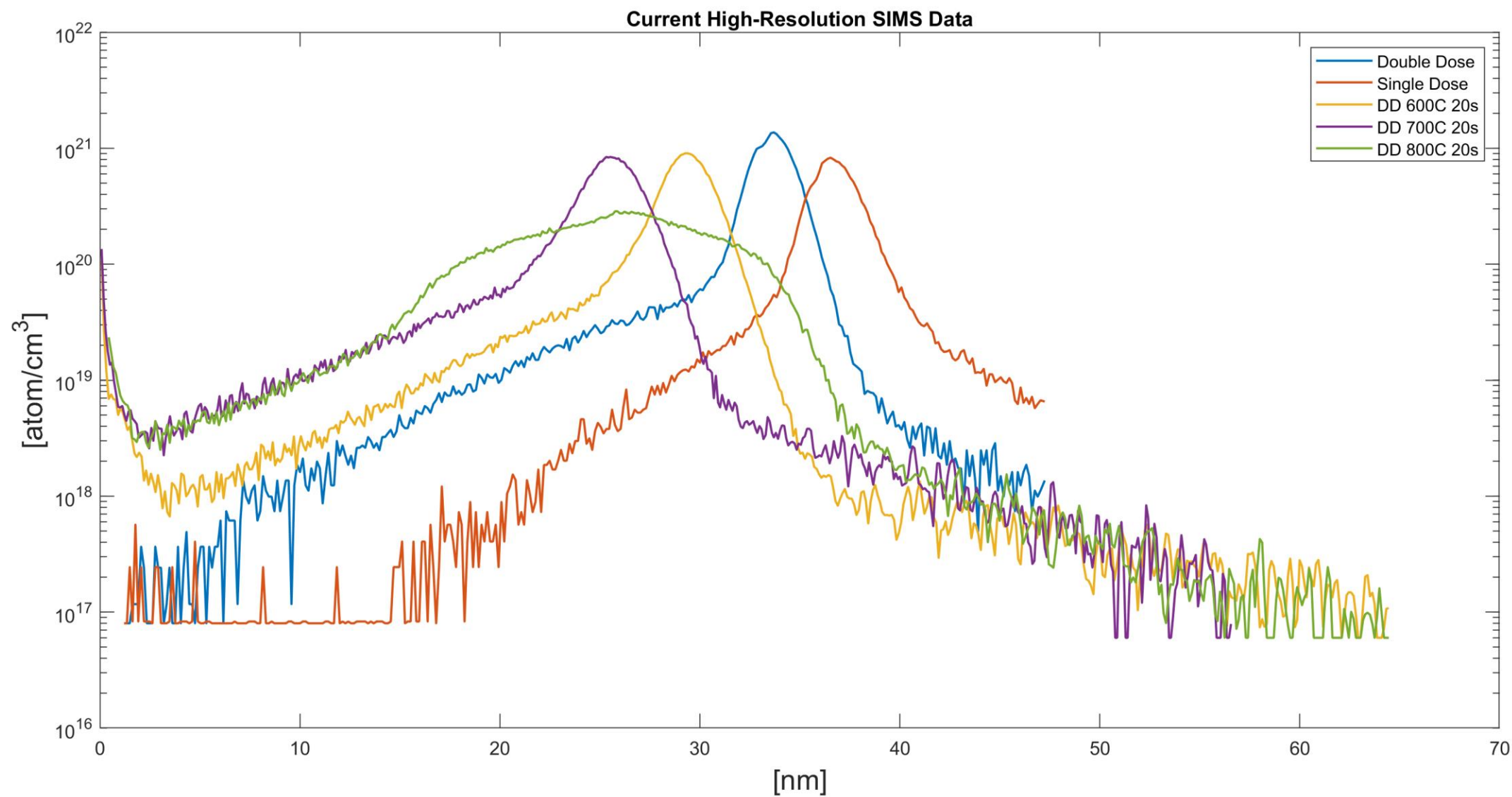


Dose: 3.8556E14 [atoms/cm<sup>2</sup>]

Peak Concentration: 1.36973E21 [atoms/cm<sup>3</sup>]

Full Width at Half Max: 2.3 +/- 0.1 [nm]

# Current Library of High-Resolution SIMS Data



# Current Library of High-Resolution SIMS Data

Sample	Peak Concentration [atoms/cm <sup>3</sup> ]	Dose [atoms/cm <sup>2</sup> ]	Full Width at Half Max (FWHM) [nm]
<b>Double Dose As Grown</b>	<b>1.36973E21</b>	<b>3.8556E14</b>	<b>2.3</b>
<b>Double Dose 600C 20s</b>	<b>9.046E20</b>	<b>3.1445E14</b>	<b>2.7</b>
<b>Double Dose 700C 20s</b>	<b>8.408E20</b>	<b>3.5298E14</b>	<b>3.2</b>
<b>Double Dose 800C 20s</b>	<b>2.858E20</b>	<b>3.4120E14</b>	<b>11.9</b>